Light-tunable, low-dimensional materials for futuristic electronics, optoelectronics and braininspired devices

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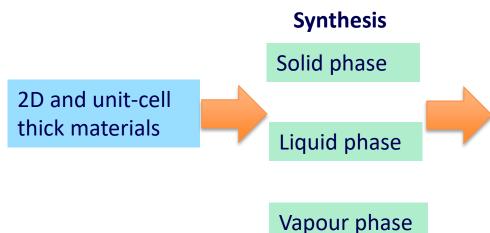
Research Focus Areas

Our current research activities include

- Electronic materials synthesis (Two-dimensional Materials)
- Light-matter interactions for photodetectors and neuromorphics
- Stitching heterostructures of dissimilar materials
- Biomaterials for antipathogenic coatings
- Stretchable and flexible devices
- Biomarker detection using versatile sensing platforms
- Research Industry Partnerships



Low-dimensional materials



Applications



Electronics

FETs, memory devices

Optoelectronics

Photodetectors, LEDs Light-driven artificial neural networks



Flexible devices
Strain engineering of 2D materials

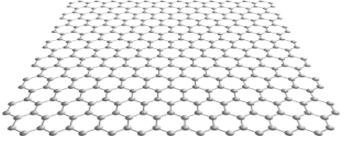
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Antipathogenic coatings Antibacterial and antifungal

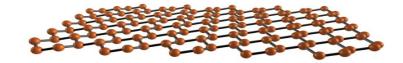


2D Materials

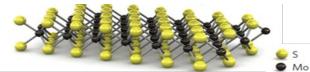
2D materials – Free standing, atomically thin single layer of a layered material.



Graphene



Silicene





Molybdenum disulphide



Nature Nanotechnology 9, 330-331 (2014) DOI: 10.1038/nnano.2014.85

phosphorene



Phosphorene?

Exists in a layered crystal form (Black phosphorus)

Allows easy exfoliation of layers.

Thickness dependent bandgap

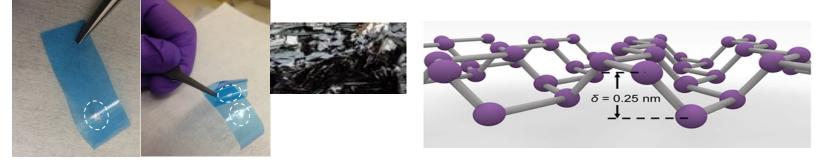
Exhibits a natural direct bandgap, which increases with reducing thickness

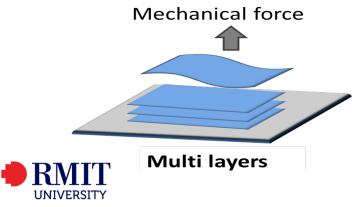
Highly flexible

Young's modulus smaller than graphene



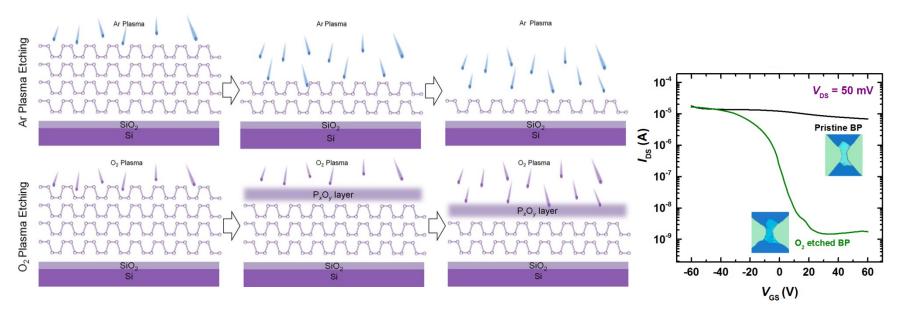
Production of phosphorene





Few-layer phosphorene can be obtained by mechanical exfoliation of black phosphorus

Thickness-control



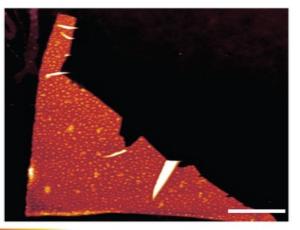


Problem with phosphorene

Degrades rapidly in an ambient environment

Initial reports suggested humidity causes degradation





0 nm

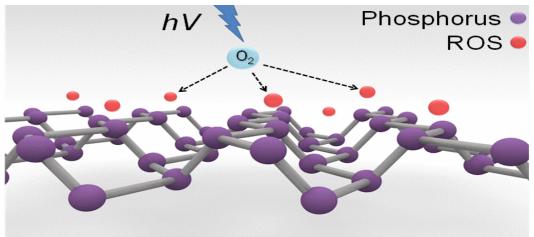
25 nm



What degrades phosphorene

Photo-oxidation does!!

Humidity facilitates this process

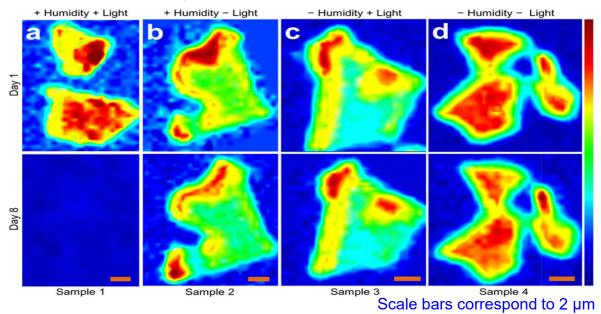




Walia et al., <u>2D Materials</u>, 2016, 4, 015025 Walia et al., <u>Advanced Materials</u>, 2017 (10.1002/adma.201700152) Ahmed et al., <u>NPJ 2D Materials and Applications</u>, 2017 1, 18

Light plays key role in phosphorene degradation

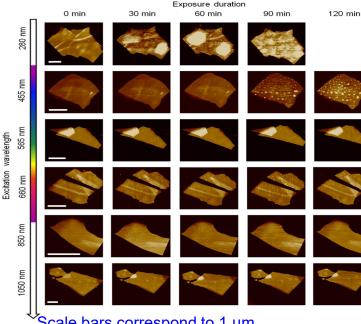
Humidity expedites the process!



In fact, phosphorene can be used in humidity sensors when operated in dark

Walia et al., <u>2D Materials</u>, 2016, 4, 015025

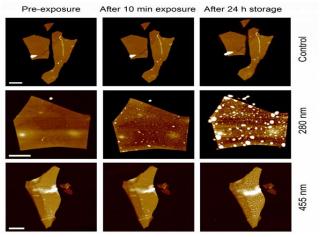
Which wavelength causes fastest degradation?



Scale bars correspond to 1 µm

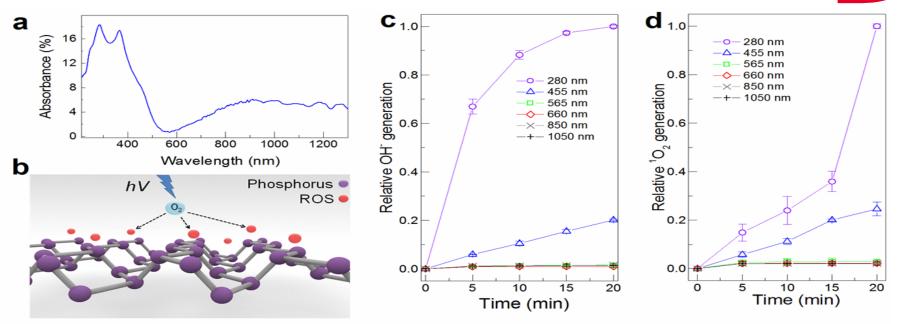


UV should be blamed for phosphorene degradation



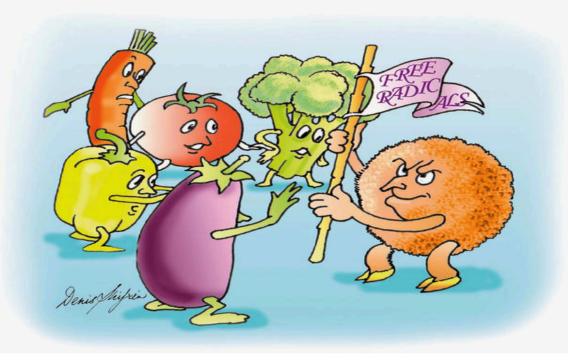
Short bursts of blue light are OK

Why light causes rapid degradation?





So how can we prevent phosphorene from these damaging oxygen species ?





Anti-oxidant Ionic liquids (ILs) are effective

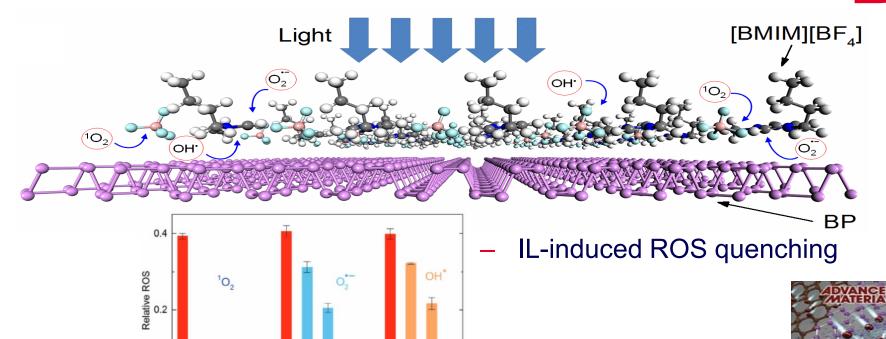
UNIVERSITY

0.0

0 10-15 10-12 10-9

0 10-3 10-2 10-1

Molar Concentration

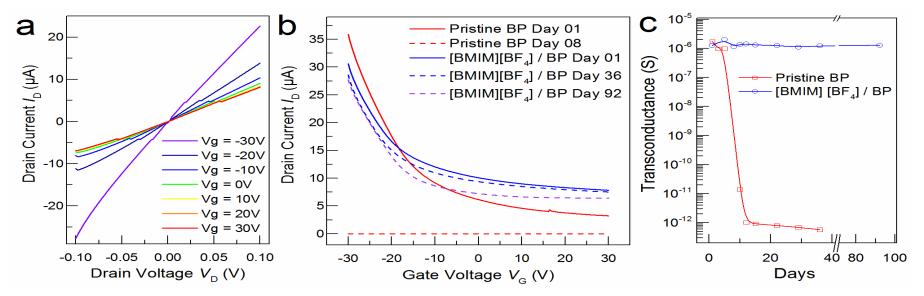


0 10-3 10-2 10-1

. –

Advanced Materials, (10.1002/adma.201700152)

IL protected phosphorene retains electronic characteristics for over 3 months

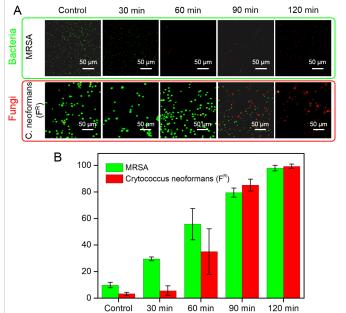




Advanced Materials, (10.1002/adma.201700152)

Exploiting reactive oxygen species for functionality

- Antibacterial and antifungal action



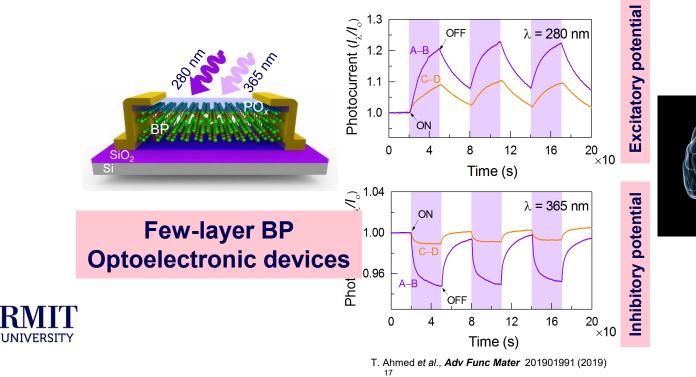
- Confocal laser scan microscope imaging
- Green and red nucleic acid and propidium iodide (PI) stains
- PI only permeates damaged cell membranes and bind in higher affinity to nucleic acid to replace the green stain



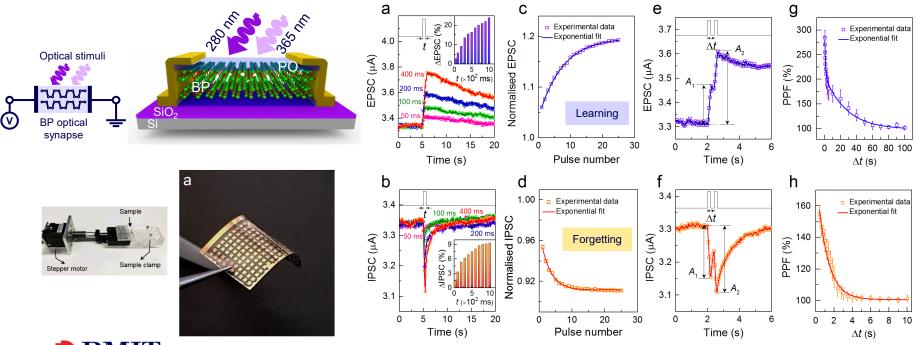
Microbial viability as a function of time. A) Time-lapse CLSM images of MRSA and fluconazole resistant *Cryptococcus neoformans* (F) cells following exposure to Black Phosphorus. **B)** Antimicrobial performance was quantified as a percentage of dead cells from the CLSM images a function of time.

Unpublished results

Can we use light in electronic devices to mimic Excitatory & Inhibitory action potentials of a synapse?



Black Phosphorus | Optoelectronic synaptic devices

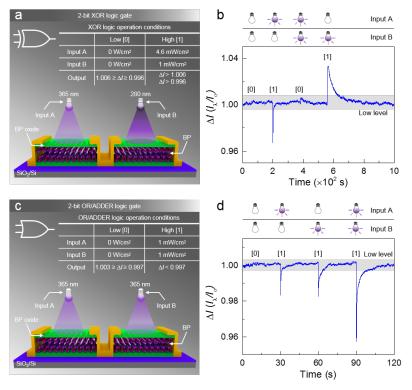




excitatory postsynaptic current (EPSC) and inhibitory postsynaptic current (IPSC) pair-pulse-facilitation (PPF) for dynamic synaptic plasticity

Black Phosphorus | Optical logic devices

- Optical Boolean logic in serially connected devices
 - Utilising 280nm and 365nm wavelengths
- □ 2-bit XOR logic
 - 280nm and 365nm inducing similar but opposite magnitude of change in output photocurrent
- □ 2-bit OR logic
 - Possible with either 280nm or 365nm
 - Both inputs augment net change in output photocurrent



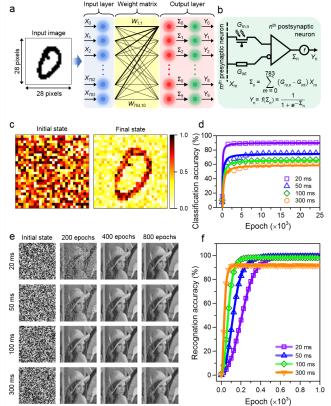


Artificial neural networks |

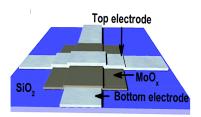
- Can mimic long-term potentiation and depression
- Optical WRITE (280 nm) and Optical ERASE (365 nm) without using electrical gating

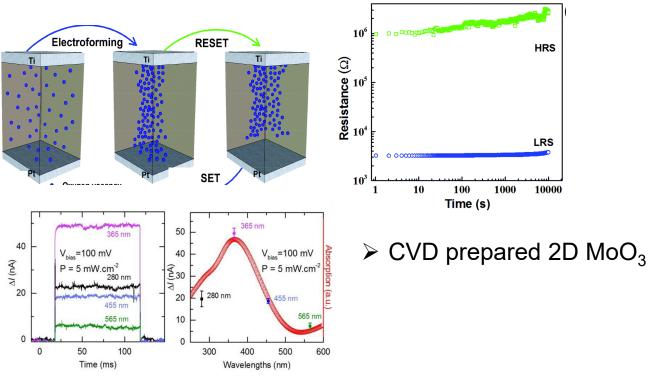


Pattern and image recognition



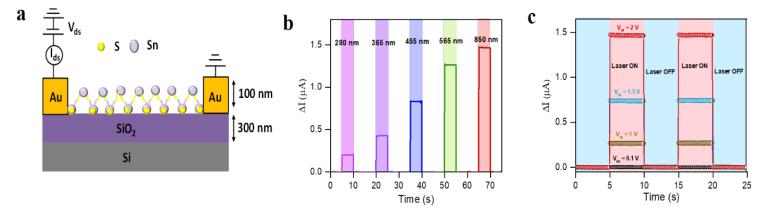
Memristors and UV detectors | Layered 2D MoO₃ films







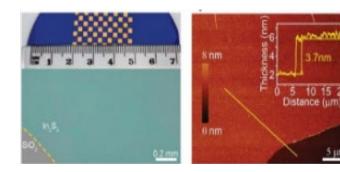
SnS based high-speed, broadband photodetectors

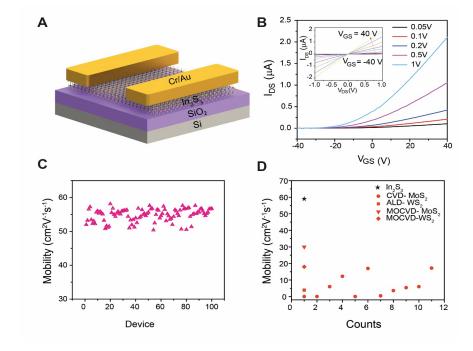


- \blacktriangleright µs fast response using 0.8-1.8 nm thick sheets
- Broadband (280-850 nm)
- One of the highest responsivities and detectivities for similar thickness systems



In₂S₃ based Field-effect transistors

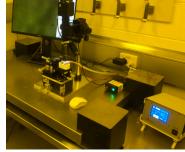






Heterostructures and large-area ultra-thin sheets







Alignment stage for heterostructures



Maskless lithography

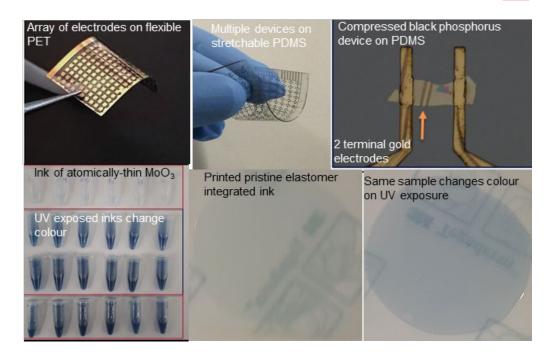


3-zone CVD

We synthesize most 2D materials in liquid phase too

Integration of 2D materials with flexible, elastomeric platforms

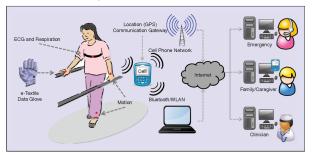
- Strain manipulation
- Printed chromic inks

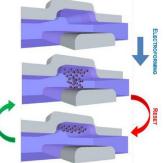




Other areas of research – Oxide thin films

Wearable sensors (Pressure and biometrics)

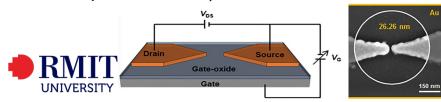




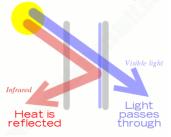
Oxide Memristors (Multi-state memory storage)



Semiconductor-free transistors (air-channel as transport channel)

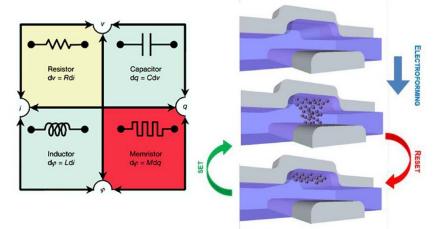


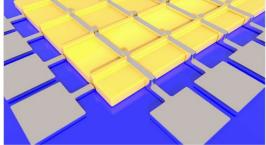
Smart coatings for infrared control Summer day



www.explainthatstuff.com

Memristors | Amorphous Complex Oxides







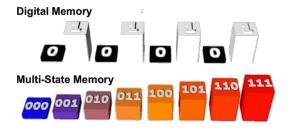


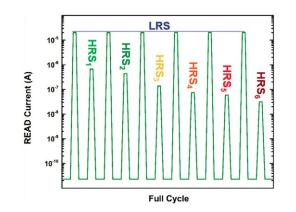
Adv. Funct. Mater. 24 6741 (2014); *Adv. Funct. Mater.* 25 3172 (2015); *Nanotechnol.* 27 505210 (2016). International PCT Patent Application No. PCT/AU2016/051145; Australian Provisional Patent 2016902654.

Memristors | Nanoscale Switching

- Memory behaviour relies on prior information
 - Learns from experience
- Resistance to store information
 - Can attain multiple information states
- Long-term stability
 - Years to decades without data loss
- Ultra-high density
 - Memory elements as small as 2-4 nm
- Low power technology
 - Make devices last longer
 - Near-zero power in 'off' state





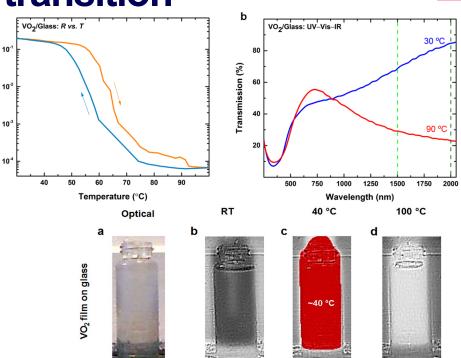


Adv. Funct. Mater. 24 6741 (2014); Adv. Funct. Mater. 25 3172 (2015); Nanotechnol. 27 505210 (2016). International PCT Patent Application No. PCT/AU2016/051145; Australian Provisional Patent 2016902654.

VO₂ enabled phase-transition

Resistivity (Ω.m)

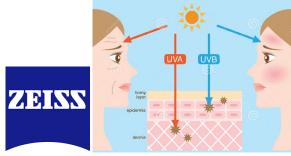
- Ability to fabricate on a variety of substrates (glass, quartz, silicon, PDMS)
- IMT ratio: ~10⁴
- >60% optical change in the infrared region
- Smart-windows and masking of infrared signatures





Wearing the Future | Applications

UV Sensors



Biometrics/Health Markers





Smart bedding for aged-care







Technology capability areas

Our current research activities include

- Synthesis of atomically thin materials
- Photodetectors (detecting different wavelengths of light on demand)
- Artificial neural networks
- Engineering Light blocking layers (Transmit and block selective wavelength bands on demand)
- Wireless electronics on wearable and stretchable platforms
- Communication of sensors to smart devices wirelessly
- Specific Biomarker sensors (saliva, sweat etc). We engineer selective sensors based on target biomarker
- Antibacterial and antifungal coatings



Our facilities







Acknowledgements

NUTLONICS PERSONALISED NUTRITION

5 sleeptite

Sleepeezee









Australian Government Department of Industry, Innovation and Science



Get in touch for possible collaborations and partnerships!!

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